Capture ultrafast atom dimerization and rotation dynamic pathways

Scientific Achievement

We discover unexpected nonlinear atomic motion trajectories during the early stage of the insulator-metal transition (IMT) in vanadium dioxide.

Significance and Impact

The gigantic resistivity change accompanying the IMT can be used to emulate neurons or synapses in human brains. Understanding IMT dynamics allows us to develop devices for high speed, high accuracy and low energy-consumption neuromorphic computing.

Research Details

- Using MeV-UED we accurately map the atomic motion trajectories through quantitative analysis of diffraction intensity and structure refinements.
- Ab-initio molecular dynamics calculations support the experimental findings and identify the phonons coupling to photoexcitation.

Topological Hall Effect Anisotropy in Kagome Bilayer Metal Fe$_3$Sn$_2$

**Scientific Achievement**

Large topological Hall effect and detection of skyrmions for interlayer current and in plane magnetic field.

**Significance and Impact**

The effect is present at high temperatures in micron size crystals typically used in devices.

**Research Details**

- Single crystals of Fe$_3$Sn$_2$ were grown by the high temperature self-flux method at CMPMSD and fabricated using focused ion beam at CFN in mesoscopic size for transport and Lorentz transition electron microscopy (TEM) studies.
- Topological Hall effect is linked to field-induced anisotropy and reorientation in magnetic structure that influences noncollinear spin texture with nonzero scalar spin chirality.
- Spin reorientation and skyrmionics bubbles are confirmed by Lorentz TEM, for the first time when magnetic field is in Kagome planes.

- Topological Hall effect with (a) current along c axis and magnetic field inside Kagome plane and (b) current inside Kagome plane and magnetic field along c axis.

*Qianheng Du, Zhixiang Hu, Myung-Geun Han, Fernando Camino, Yimei Zhu and C. Petrovic, Physical Review Letters 129, 236601 (2022).*

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  - Spin reorientation and skyrmionics bubbles are confirmed by Lorentz TEM, for the first time when magnetic field is in Kagome planes.
Scientific Achievement

Conduction in magnetic two-dimensional van der Waals (2D vdW) Cr$_2$Ge$_2$Te$_6$ crystals is enhanced by stacking fault crystal structure distortion.

Significance and Impact

This opens possibility for manipulation of charge transport by electron-phonon and spin-orbit coupling-based tailoring of polaron properties.

Research Details

- Transmission electron microscopy (TEM) imaging reveals stacking faults of vdW layers with about 0.027 nm$^{-1}$ density.
- Conduction states are involved in polaronic transport via hopping and are sensitive on details of magnetocrystalline anisotropy.

Photoinduced transient state in thermoelectric SnSe

Scientific Achievement

We reveal photoinduced anharmonic lattice distortion that leads to a transient domain state only surviving for ~20ps at 90K.

Significance and Impact

Lattice manipulation via ultrafast laser pulses can introduce novel phonon scattering centers that reduce thermal conductivity and improve the performance of thermoelectric materials.

Research Details

- Femtosecond laser and MeV-UED were used to induce lattice distortion and probe the lattice response dynamics.
- A Monte Carlo based multislice diffraction simulation method as developed to interpret the observed asymmetrical diffuse Huang scattering near the Bragg peaks.
- DFT calculations suggest the distortions correspond to a superposition of a few special phonon modes with strong anharmonicity and phonon scattering.

Scientific Achievement

We reveal a functional role played by planar-defect in the ferroelectric domain switching.

Significance and Impact

*In situ* TEM experiments revealed shear-strain-induced nucleation and symmetric domain switching at the structural antiphase boundary in ferroelectric thin films. This study shows that an extended structural defect can be used as an active switching element in reprogrammable domain-wall-based electronic devices.

Research Details

- *In situ* electric biasing in TEM was utilized to extensively study the influence of an antiphase boundary on the switching behavior in a (110)-oriented BiFeO$_3$ thin film.
- Atomic-scale structural analysis including unit-cell shift, lattice parameter, and Fe-displacement are carried out to reveal the structural origins for the symmetric switching.

Capture photon-induced transition form topological insulator to Dirac semimetal

(Left panel) Schematic of the ZrTe\textsubscript{5} crystal structure showing Te3 lattice displacement (red arrows) along the c-axis in its photoinduced transient state. (Right panel) The direct-gaps at \textGamma point for two Te3 positions derived by DFT. There is a small gap before photoexcitation (top, insulating state). The gap is closed in the presence of strong spin-orbit coupling after photoexcitation (bottom, Semimetal state).

Scientific Achievement
Using photoexcitation to manipulate and control material’s emerging behavior and functionality.

Significance and Impact
Revealing the femtosecond photon-induced changes in local atomic bond length of ZrTe\textsubscript{5} leads to electronic topological phase transition.

Research Details
- Quantitative ultrafast electron diffraction analysis via structure refinement to determine atom positions of the photoexcited transient state without structural symmetry breaking
- With experimentally determined lattice displacements DFT calculations reveal how a transient Dirac semimetal state can be induced by photoexcitation in a topological insulator
- Unraveling two timescales related to electron, spin and lattice coupling and correlations.

"Photoinduced chiral Dirac semimetal in ZrTe\textsubscript{5}", npj Quantum Materials, 5:80, 1-8 (Nov. 2020).
Two-color near-field UEM at nm-fs resolution

Scientific Achievement

Using two-color photoinduced nearfield electron microscopy (PINEM) to achieve $10^{-21}$ m·s spatiotemporal resolution for ultrafast electron microscopy (UEM)

Significance and Impact

The novel approach allows a spatiotemporal resolution several orders of magnitude better than the conventional optical probes and static imaging, enabling direct visualization of ultrafast dielectric response in Mott insulators and I-M transitions in quantum materials.

Research Details

- The 50fs optical pulses split into two, one for gating via PINEM and the other for pumping to improve resolution.
- Spatially mapping nearfield dynamics of single VO$_2$ nanowires was compared with theory, revealing ultrafast photo-doping drives the system into a metallic state on a timescale of ~150 fs without yet perturbing the crystalline lattice.

Scientific Achievement
Development of the laser-free frequency-tunable electron pulser and its first application of time-resolved direct visualization of electromagnetic (EM) wave dynamics.

Significance and Impact
The electron pulser can be retrofit into any conventional microscope for ultrafast electron microscopy (UEM) without compromising its original performance and requiring expensive fs lasers. The ability of visualizing GHz EM wave propagation allows the study of electrodynamics in devices for information transmission/processing technology.

Research Details
- The pulser consists of a modulator and a demodulator ($K_1, K_2$) with an aperture between them to chop a continuous beam into RF pulses with a tunable repetition rate.
- A prototype sample was fabricated to reveal the transient oscillating EM field around the tines of the combs, time-resolved polarization and field distributions. Numerical simulations of the wave dynamics were also incorporated.

Scientific Achievement

We demonstrate the first room-temperature thermoelectric signature of skyrmion bubbles in a simple thermal gradient. This is observed in Fe$_3$Sn$_2$, a Kagome Dirac crystal with massive Dirac fermions.

Significance and Impact

Nanoscale magnetic skyrmions are quintessential embodiment of strong electronic correlations and topology. The results pave the way for future information storage and spin caloritronic devices using skyrmion manipulation by thermal gradients.

Research Details

- Phonon- or magnon-drag contribute at low temperatures but room-temperature thermopower is dominated by electronic diffusion, allowing for the skyrmionics bubble detection.
- Transmission electron microscopy imaging of the magnetic spin textures at room temperature confirms that skyrmionics bubbles are induced in external magnetic field at (600 – 800) mT where thermoelectric anomaly is observed.

Qianheng Du, Muyng-Geun Han, Yu Liu, Weijun Ren, Yimei Zhu and C. Petrovic “Room-Temperature Skyrmion Thermopower in Fe$_3$Sn$_2$” Advanced Quantum Technologies, 2000058, 1-6 (2020).
Scientific Achievement
Systematic study on topological chiral spin textures and their transitions reveals two novel phenomena: anisotropic scaling in helix and skyrmion channeling.

Significance and Impact
Novel spin behaviors provide a viable way towards controlled manipulation of helices and skyrmion lattices, envisaging chirality-controlled skyrmion-based spintronic devices.

Research Details
- Topological spin textures, helices and skyrmions, and their transitions in multiferroic Cu$_2$OSeO$_3$ are manipulated and controlled by varying magnetic field, temperature, material thickness and chemical doping. Their spin structures are characterized by cryogenic Lorentz phase microscopy.
- Rotation of spin helix (scaling) and gradual filling of skyrmions (channeling) from thinner to thicker sections are observed with increasing magnetic field.

Scientific Achievement

We report a deterministic ferroelastic domain switching in ferroelectric bilayers and revealed its underlying switching mechanisms and physical origins for dramatically enhanced electromechanical responses ($d_{33} \sim 300 \text{ pm/V}$).

Significance and Impact

Beyond simple observation of electric-field-induced ferroelastic domain walls, reproducible reorientation of ferroelastic domain walls reported in this study provides a viable pathway toward designing electromechanical devices based on programmable ferroelastic domain walls.

Research Details

- Using *in situ* electrical biasing in transmission electron microscope ferroelastic domain switching process are revealed in ferroelectric bilayers.
- Switching pathways including nucleation sites and polarization rotations are elucidated by atomic resolution imaging and confirmed by phase field simulation.